

updated search

L Number	Hits	Search Text	DB	Time stamp
1	1013	("257/401").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:39
2	79	("257/135").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:39
3	124	("257/491").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:39
4	76	("257/492").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:39
5	83	("257/493").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:39
6	64	("438/212").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:39
7	193	("438/259").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:39
8	1391	("438/270").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:40
9	321	("438/271").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:40
10	231	("438/587").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:40
11	141	("438/588").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:40
12	205	("438/589").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:40
13	0	("L1 or L2 or L3 or L4 or L5 or L6 or L7 or L8 or L9 or L10").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:40

14	3400	((("257/401").CCLS.) or ((("257/135").CCLS.) or ((("257/491").CCLS.) or ((("257/492").CCLS.) or ((("257/493").CCLS.) or ((("438/212").CCLS.) or ((("438/259").CCLS.) or ((("438/270").CCLS.) or ((("438/271").CCLS.) or ((("438/587").CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:50
15	274	((("257/401").CCLS.) or ((("257/135").CCLS.) or ((("257/491").CCLS.) or ((("257/492").CCLS.) or ((("257/493").CCLS.) or ((("438/212").CCLS.) or ((("438/259").CCLS.) or ((("438/270").CCLS.) or ((("438/271").CCLS.) or ((("438/587").CCLS.)) and ((groove or trench) near15 insulat\$3 adj2 (layer or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:53
16	329	((("257/401").CCLS.) or ((("257/135").CCLS.) or ((("257/491").CCLS.) or ((("257/492").CCLS.) or ((("257/493").CCLS.) or ((("438/212").CCLS.) or ((("438/259").CCLS.) or ((("438/270").CCLS.) or ((("438/271").CCLS.) or ((("438/587").CCLS.)) and (groove or trench) adj2 gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:54
17	81	((((("257/401").CCLS.) or ((("257/135").CCLS.) or ((("257/491").CCLS.) or ((("257/492").CCLS.) or ((("257/493").CCLS.) or ((("438/212").CCLS.) or ((("438/259").CCLS.) or ((("438/270").CCLS.) or ((("438/271").CCLS.) or ((("438/587").CCLS.)) and (groove or trench) adj2 gate) and base adj2 (region or layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:56
18	81	((((("257/401").CCLS.) or ((("257/135").CCLS.) or ((("257/491").CCLS.) or ((("257/492").CCLS.) or ((("257/493").CCLS.) or ((("438/212").CCLS.) or ((("438/259").CCLS.) or ((("438/270").CCLS.) or ((("438/271").CCLS.) or ((("438/587").CCLS.)) and (groove or trench) adj2 gate) and (n-base or p-base or p adj base or n adj base or base) adj2 (region or layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 14:31
19	24	hamada.in. and trench	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 14:38
20	3071	((trench or groove) near3 gate)	EPO; JPO; DERWENT; IBM TDB	2002/02/01 14:39
21	629	((trench or groove) near3 gate) and conduct\$5 and semiconduct\$5	EPO; JPO; DERWENT; IBM TDB	2002/02/01 14:40
22	612	((trench or groove) near3 gate) and conduct\$5 and semiconduct\$5.ti,ab.	EPO; JPO; DERWENT; IBM TDB	2002/02/01 14:40
23	598	((trench or groove) near3 gate).ti,ab. and conduct\$5 and semiconduct\$5.ti,ab.	EPO; JPO; DERWENT; IBM TDB	2002/02/01 14:49
24	120	((trench or groove) near3 gate).ti,ab. and conduct\$5 and semiconduct\$5.ti,ab. and connect\$3	EPO; JPO; DERWENT; IBM TDB	2002/02/01 15:12
25	1	5861649.pn.	USPAT	2002/02/01 14:59
26	1	6118150.pn.	EPO; JPO; DERWENT; IBM TDB	2002/02/01 15:12
27	1	6118150.pn.	USPAT	2002/02/01 15:12

-	0	257/\$5.ccls. and breakdown and avalanche and low adj on adj resistance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:32
-	0	257/\$5.ccls. and breakdown and low adj on adj resistance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 07:58
-	321	257/\$5.ccls. and breakdown and low adj2 resistance and latch\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 07:59
-	15	257/\$5.ccls. and breakdown and low adj2 resistance and latch\$3 and avalanche and trench	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 07:59
-	15	257/\$5.ccls. and breakdown and low adj2 resistance and latch\$3 and avalanche and trench and power	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 08:10
-	0	(257/\$5.ccls. and breakdown and low adj2 resistance and latch\$3 and avalanche and trench and power) and hamada.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 08:00
-	8	257/\$5.ccls. and breakdown and low adj2 resistance and latch\$3 and avalanche and trench and power and igbt	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 08:35
-	3	257/\$5.ccls. and breakdown and low adj2 resistance and latch\$3 and avalanche and trench and power and igbt and rie	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 08:37
-	562	vertical near4 mosfet.ti.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 13:15
-	0	vertical near4 mosfet.ti. and drift adj drain.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 13:15
-	0	vertical near4 mosfet.ti. and drift adj2 drain	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 13:15
-	7	vertical near4 mosfet.ti. and (drift near4 drain)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 13:15
-	36	semiconducting adj polymer same polyaniline	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 16:53
-	0	semiconducting adj polymer same polyaniline and 106/\$5.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 16:53

-	356	("257/329").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:33
-	568	("257/330").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:33
-	280	("257/331").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:33
-	239	("257/332").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:33
-	525	("257/341").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:33
-	284	("257/342").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:33